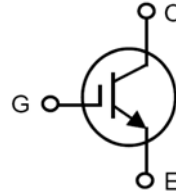


# High Voltage XPT™ IGBT

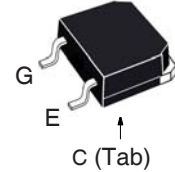
## IXYT25N250CHV IXYH25N250CHV

$$\begin{aligned} V_{CES} &= 2500V \\ I_{C110} &= 25A \\ V_{CE(sat)} &\leq 4.0V \\ t_{fi(typ)} &= 246ns \end{aligned}$$

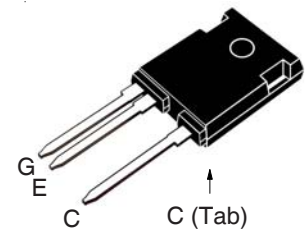


| Symbol                  | Test Conditions                                                                     | Maximum Ratings |                  |
|-------------------------|-------------------------------------------------------------------------------------|-----------------|------------------|
| $V_{CES}$               | $T_J = 25^\circ\text{C to } 175^\circ\text{C}$                                      | 2500            | V                |
| $V_{CGR}$               | $T_J = 25^\circ\text{C to } 175^\circ\text{C}, R_{GE} = 1M\Omega$                   | 2500            | V                |
| $V_{GES}$               | Continuous                                                                          | $\pm 20$        | V                |
| $V_{GEM}$               | Transient                                                                           | $\pm 30$        | V                |
| $I_{C25}$               | $T_C = 25^\circ\text{C}$                                                            | 95              | A                |
| $I_{C110}$              | $T_C = 110^\circ\text{C}$                                                           | 25              | A                |
| $I_{CM}$                | $T_C = 25^\circ\text{C}, 1\text{ms}$                                                | 235             | A                |
| <b>SSOA<br/>(RBSOA)</b> | $V_{GE} = 15V, T_{VJ} = 150^\circ\text{C}, R_G = 5\Omega$<br>Clamped Inductive Load | $I_{CM} = 100$  | A                |
|                         |                                                                                     | 1500            | V                |
| $P_C$                   | $T_C = 25^\circ\text{C}$                                                            | 937             | W                |
| $T_J$                   |                                                                                     | -55 ... +175    | $^\circ\text{C}$ |
| $T_{JM}$                |                                                                                     | 175             | $^\circ\text{C}$ |
| $T_{stg}$               |                                                                                     | -55 ... +175    | $^\circ\text{C}$ |
| $T_L$                   | Maximum Lead Temperature for Soldering                                              | 300             | $^\circ\text{C}$ |
| $T_{SOLD}$              | Plastic Body for 10s                                                                | 260             | $^\circ\text{C}$ |
| $M_d$                   | Mounting Torque                                                                     | 1.13/10         | Nm/lb.in         |
| <b>Weight</b>           | TO-268HV                                                                            | 4               | g                |
|                         | TO-247HV                                                                            | 6               | g                |

TO-268HV (IXYT)



TO-247HV (IXYH)



G = Gate      C = Drain  
E = Source    Tab = Drain

### Features

- High Voltage Package
- High Blocking Voltage
- High Peak Current Capability
- Low Saturation Voltage

### Advantages

- Low Gate Drive Requirement
- High Power Density

### Applications

- Switch-Mode and Resonant-Mode Power Supplies
- Uninterruptible Power Supplies (UPS)
- Laser Generators
- Capacitor Discharge Circuits
- AC Switches

| Symbol        | Test Conditions<br>( $T_J = 25^\circ\text{C}$ , Unless Otherwise Specified) | Characteristic Values |            |                  |
|---------------|-----------------------------------------------------------------------------|-----------------------|------------|------------------|
|               |                                                                             | Min.                  | Typ.       | Max.             |
| $BV_{CES}$    | $I_C = 250\mu\text{A}, V_{GE} = 0V$                                         | 2500                  |            | V                |
| $V_{GE(th)}$  | $I_C = 250\mu\text{A}, V_{CE} = V_{GE}$                                     | 3.0                   |            | 5.0 V            |
| $I_{CES}$     | $V_{CE} = V_{CES}, V_{GE} = 0V$<br>$T_J = 100^\circ\text{C}$                |                       | 100        | 25 $\mu\text{A}$ |
| $I_{GES}$     | $V_{CE} = 0V, V_{GE} = \pm 20V$                                             |                       |            | $\pm 100$ nA     |
| $V_{CE(sat)}$ | $I_C = 25A, V_{GE} = 15V$ , Note 1<br>$T_J = 150^\circ\text{C}$             |                       | 3.4<br>4.7 | 4.0 V<br>V       |

## Symbol Test Conditions

( $T_J = 25^\circ\text{C}$  Unless Otherwise Specified)

## Characteristic Values

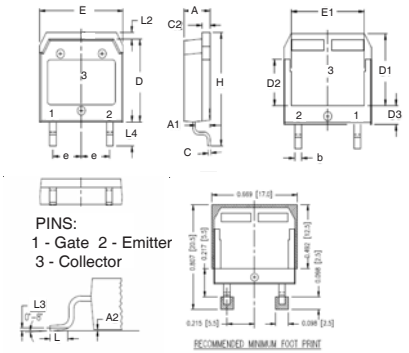
|              |                                                                                                                                                                       | Min. | Typ. | Max.               |
|--------------|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|--------------------|
| $g_{fs}$     | $I_C = 25\text{A}$ , $V_{CE} = 10\text{V}$ , Note 1                                                                                                                   | 16   | 27   | S                  |
| $R_{Gi}$     | Gate Input Resistance                                                                                                                                                 |      | 2.8  | $\Omega$           |
| $C_{ies}$    | $V_{CE} = 25\text{V}$ , $V_{GE} = 0\text{V}$ , $f = 1\text{MHz}$                                                                                                      |      | 3060 | pF                 |
| $C_{oes}$    |                                                                                                                                                                       |      | 114  | pF                 |
| $C_{res}$    |                                                                                                                                                                       |      | 43   | pF                 |
| $Q_{g(on)}$  | $I_C = 25\text{A}$ , $V_{GE} = 15\text{V}$ , $V_{CE} = 0.5 \cdot V_{CES}$                                                                                             |      | 147  | nC                 |
| $Q_{ge}$     |                                                                                                                                                                       |      | 16   | nC                 |
| $Q_{gc}$     |                                                                                                                                                                       |      | 68   | nC                 |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 25^\circ\text{C}</math></b><br>$I_C = 25\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}$ , $R_G = 5\Omega$<br>Note 2  |      | 15   | ns                 |
| $t_{ri}$     |                                                                                                                                                                       |      | 34   | ns                 |
| $E_{on}$     |                                                                                                                                                                       |      | 8.3  | mJ                 |
| $t_{d(off)}$ |                                                                                                                                                                       |      | 230  | ns                 |
| $t_{fi}$     |                                                                                                                                                                       |      | 246  | ns                 |
| $E_{off}$    |                                                                                                                                                                       |      | 7.3  | mJ                 |
| $t_{d(on)}$  | <b>Inductive load, <math>T_J = 150^\circ\text{C}</math></b><br>$I_C = 25\text{A}$ , $V_{GE} = 15\text{V}$<br>$V_{CE} = 0.5 \cdot V_{CES}$ , $R_G = 5\Omega$<br>Note 2 |      | 18   | ns                 |
| $t_{ri}$     |                                                                                                                                                                       |      | 33   | ns                 |
| $E_{on}$     |                                                                                                                                                                       |      | 11.0 | mJ                 |
| $t_{d(off)}$ |                                                                                                                                                                       |      | 225  | ns                 |
| $t_{fi}$     |                                                                                                                                                                       |      | 350  | ns                 |
| $E_{off}$    |                                                                                                                                                                       |      | 10.5 | mJ                 |
| $R_{thJC}$   |                                                                                                                                                                       |      | 0.15 | $^\circ\text{C/W}$ |
| $R_{thCS}$   |                                                                                                                                                                       |      |      | $^\circ\text{C/W}$ |

Note: 1. Pulse test,  $t \leq 300\mu\text{s}$ , duty cycle,  $d \leq 2\%$ .

## ADVANCE TECHNICAL INFORMATION

The product presented herein is under development. The Technical Specifications offered are derived from a subjective evaluation of the design, based upon prior knowledge and experience, and constitute a "considered reflection" of the anticipated result. IXYS reserves the right to change limits, test conditions, and dimensions without notice.

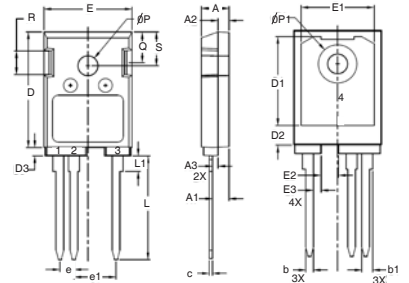
## TO-268HV Outline



PINS:  
1 - Gate 2 - Emitter  
3 - Collector

| SYM | INCHES |      | MILLIMETER |       |
|-----|--------|------|------------|-------|
|     | MIN    | MAX  | MIN        | MAX   |
| A   | .193   | .201 | 4.90       | 5.10  |
| A1  | .106   | .114 | 2.70       | 2.90  |
| A2  | .001   | .010 | 0.02       | 0.25  |
| b   | .045   | .057 | 1.15       | 1.45  |
| C   | .016   | .026 | 0.40       | 0.65  |
| C2  | .057   | .063 | 1.45       | 1.60  |
| D   | .543   | .551 | 13.80      | 14.00 |
| D1  | .465   | .476 | 11.80      | 12.10 |
| D2  | .295   | .307 | 7.50       | 7.80  |
| D3  | .114   | .126 | 2.90       | 3.20  |
| E   | .624   | .632 | 15.85      | 16.05 |
| E1  | .524   | .535 | 13.30      | 13.60 |
| E2  | .215   | BSC  | 5.45       | BSC   |
| H   | .736   | .752 | 18.70      | 19.10 |
| L   | .067   | .079 | 1.70       | 2.00  |
| L2  | .039   | .045 | 1.00       | 1.15  |
| L3  | .010   | BSC  | 0.25       | BSC   |
| L4  | .150   | .161 | 3.80       | 4.10  |

## TO-247HV Outline



PINS:  
1 - Gate 2 - Emitter  
3, 4 - Collector

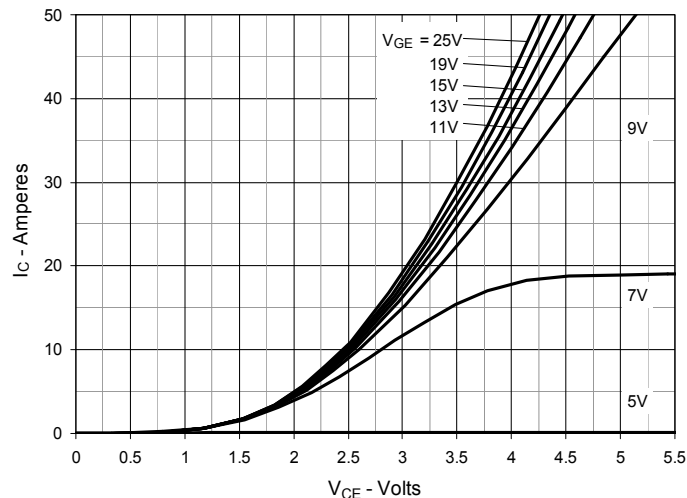
| SYM | INCHES |      | MILLIMETERS |       |
|-----|--------|------|-------------|-------|
|     | MIN    | MAX  | MIN         | MAX   |
| A   | .193   | .201 | 4.90        | 5.10  |
| A1  | .114   | .122 | 2.90        | 3.10  |
| A2  | .075   | .083 | 1.90        | 2.10  |
| A3  | .035   | .043 | 0.90        | 1.10  |
| b   | .053   | .059 | 1.35        | 1.50  |
| b1  | .075   | .083 | 1.90        | 2.10  |
| c   | .022   | .030 | 0.55        | 0.75  |
| D   | .819   | .843 | 20.80       | 21.40 |
| D1  | .638   | .646 | 16.20       | 16.40 |
| D2  | .134   | .146 | 3.40        | 3.70  |
| D3  | .055   | .063 | 1.40        | 1.60  |
| E   | .622   | .638 | 15.80       | 16.20 |
| E1  | .520   | .528 | 13.20       | 13.40 |
| E2  | .118   | .126 | 3.00        | 3.20  |
| E3  | .051   | .059 | 1.30        | 1.50  |
| e   | .100   | BSC  | 2.54        | BSC   |
| e1  | .300   | BSC  | 7.62        | BSC   |
| L   | .732   | .748 | 18.60       | 19.00 |
| L1  | .106   | .118 | 2.70        | 3.00  |
| L2  | .138   | .142 | 3.50        | 3.60  |
| L3  | .272   | .280 | 6.90        | 7.10  |
| L4  | .216   | .224 | 5.50        | 5.70  |
| L5  | .165   | .169 | 4.20        | 4.30  |
| L6  | .240   | .248 | 6.10        | 6.30  |

IXYS Reserves the Right to Change Limits, Test Conditions, and Dimensions.

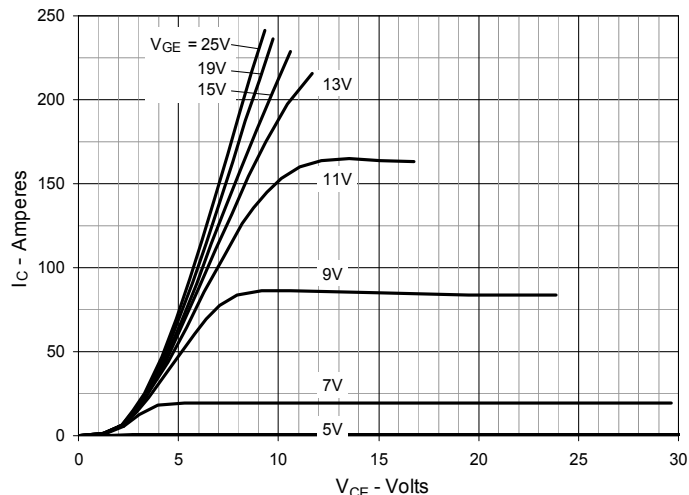
IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents:

|           |           |           |           |              |              |              |              |              |              |
|-----------|-----------|-----------|-----------|--------------|--------------|--------------|--------------|--------------|--------------|
| 4,835,592 | 4,931,844 | 5,049,961 | 5,237,481 | 6,162,665    | 6,404,065 B1 | 6,683,344    | 6,727,585    | 7,005,734 B2 | 7,157,338 B2 |
| 4,860,072 | 5,017,508 | 5,063,307 | 5,381,025 | 6,259,123 B1 | 6,534,343    | 6,710,405 B2 | 6,759,692    | 7,063,975 B2 |              |
| 4,881,106 | 5,034,796 | 5,187,117 | 5,486,715 | 6,306,728 B1 | 6,583,505    | 6,710,463    | 6,771,478 B2 | 7,071,537    |              |

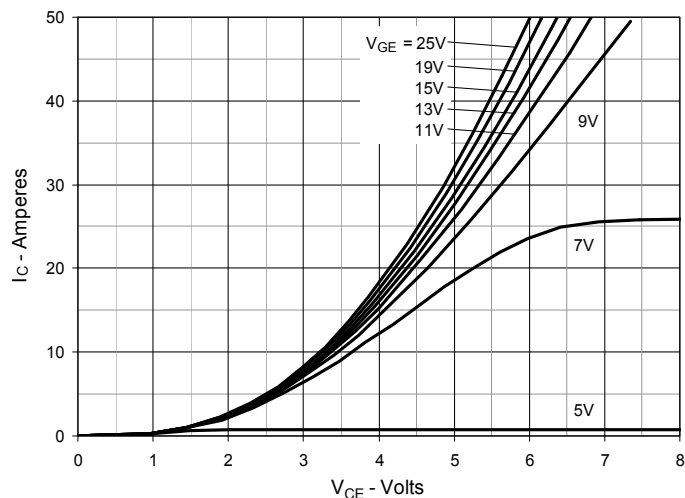
**Fig. 1. Output Characteristics @  $T_J = 25^\circ\text{C}$**



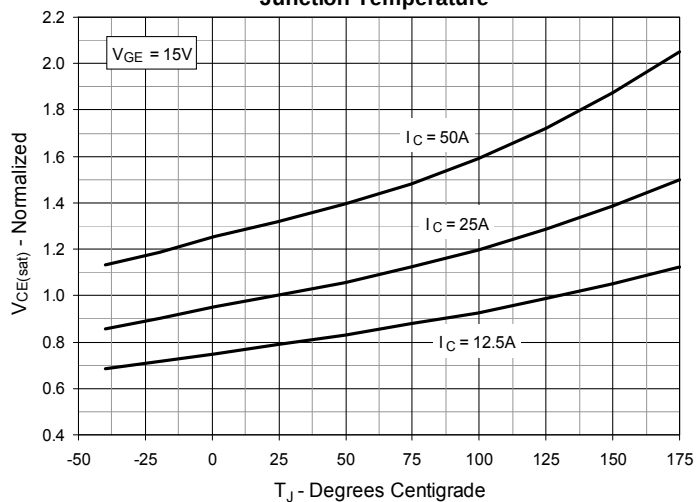
**Fig. 2. Extended Output Characteristics @  $T_J = 25^\circ\text{C}$**



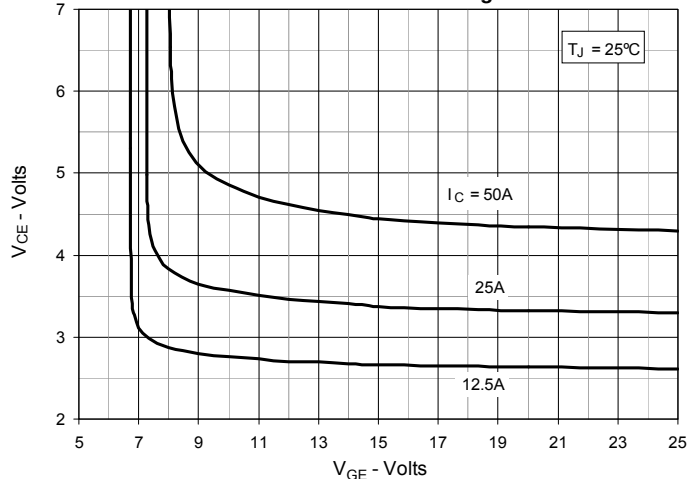
**Fig. 3. Output Characteristics @  $T_J = 150^\circ\text{C}$**



**Fig. 4. Dependence of  $V_{CE(sat)}$  on Junction Temperature**



**Fig. 5. Collector-to-Emitter Voltage vs. Gate-to-Emitter Voltage**



**Fig. 6. Input Admittance**

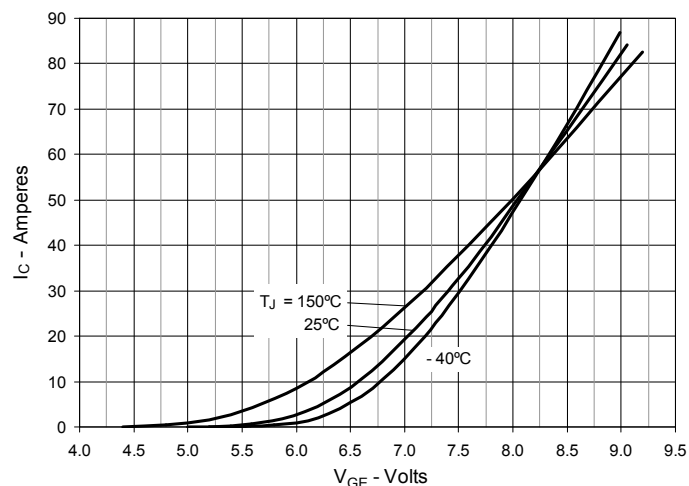


Fig. 7. Transconductance

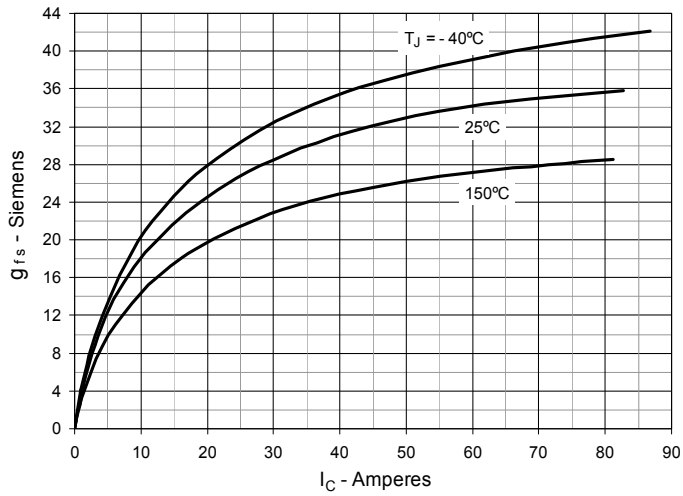


Fig. 8. Gate Charge

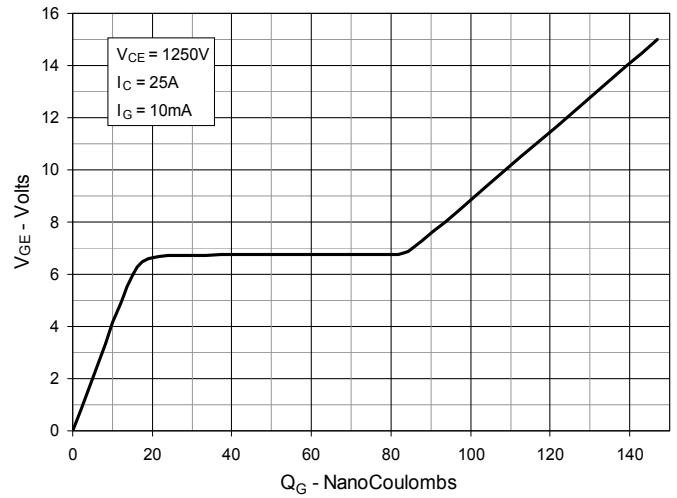


Fig. 9. Capacitance

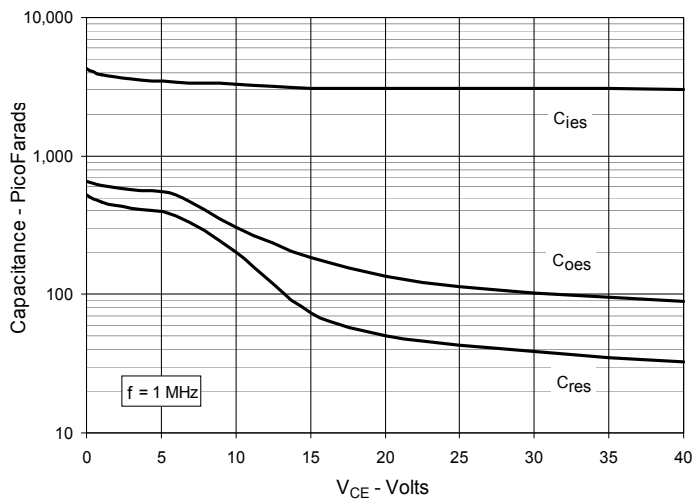


Fig. 10. Reverse-Bias Safe Operating Area

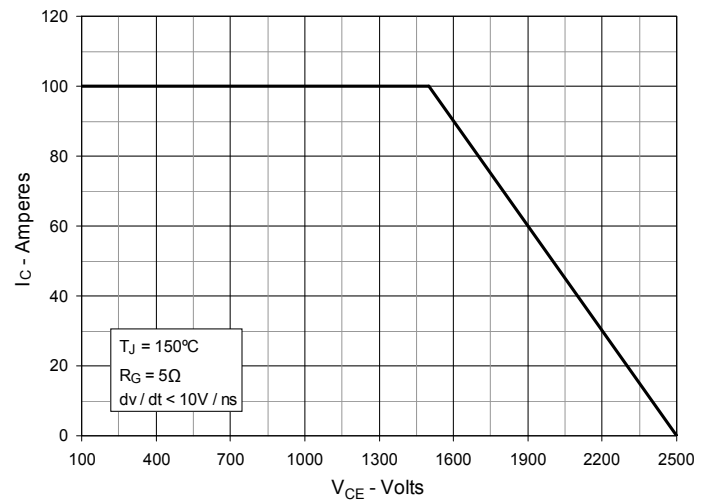


Fig. 11. Forward-Bias Safe Operating Area

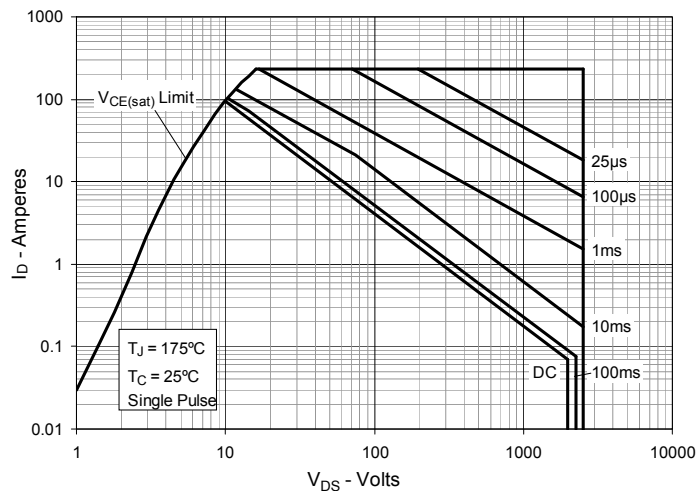


Fig. 12. Maximum Transient Thermal Impedance

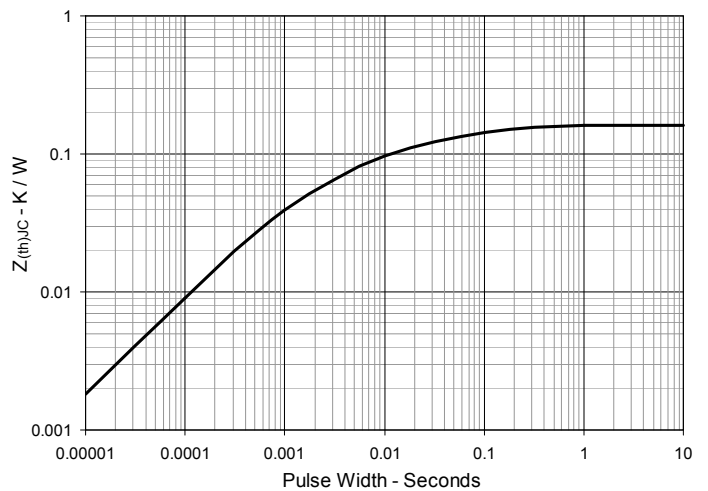


Fig. 13. Inductive Switching Energy Loss vs. Gate Resistance

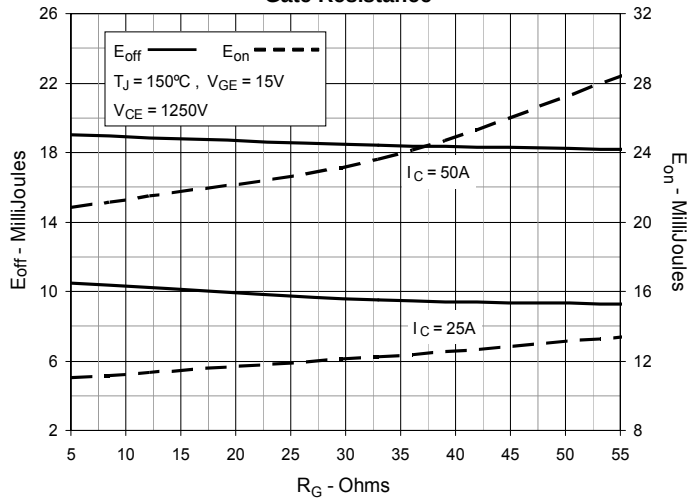


Fig. 14. Inductive Switching Energy Loss vs. Collector Current

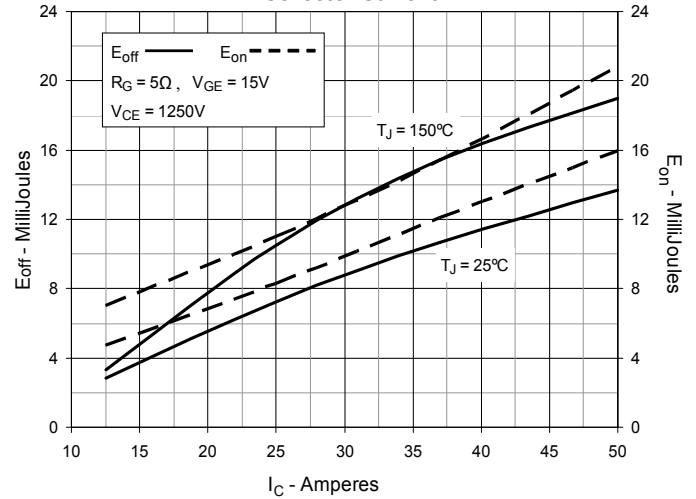


Fig. 15. Inductive Switching Energy Loss vs. Junction Temperature

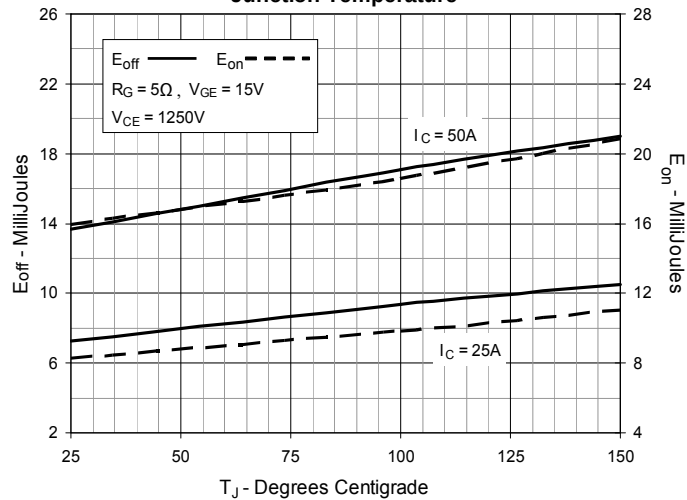


Fig. 16. Inductive Turn-off Switching Times vs. Gate Resistance

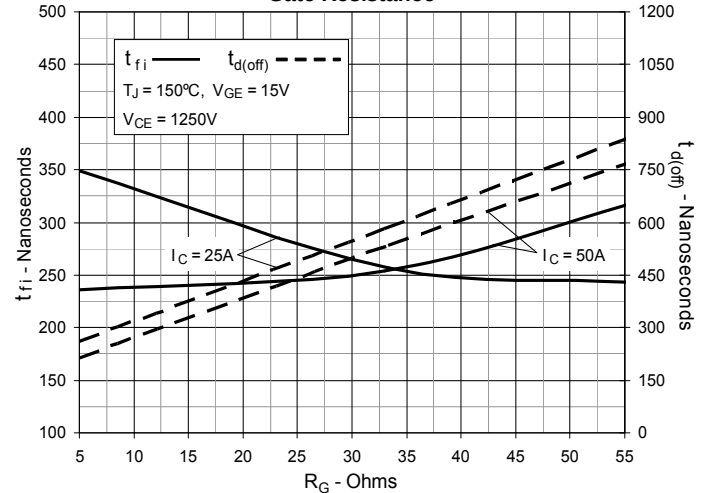


Fig. 17. Inductive Turn-off Switching Times vs. Collector Current

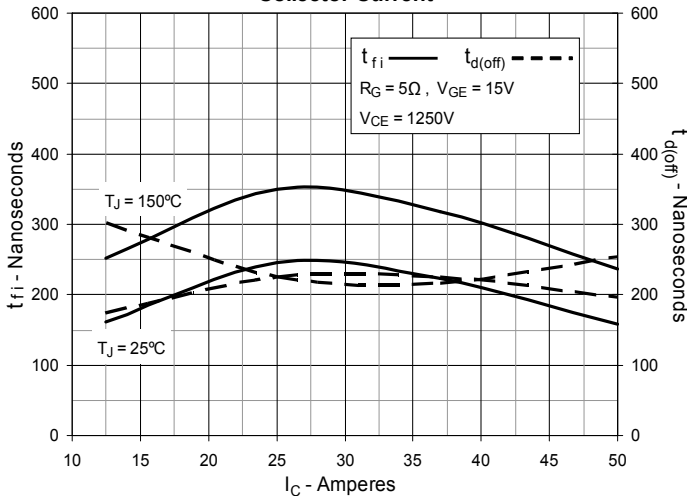
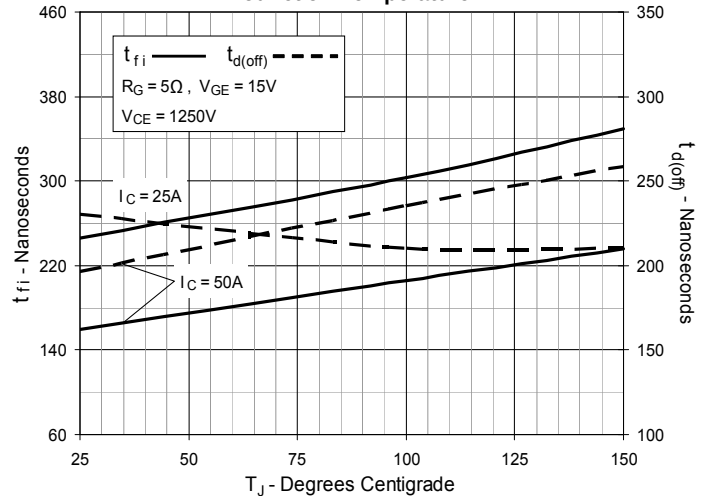
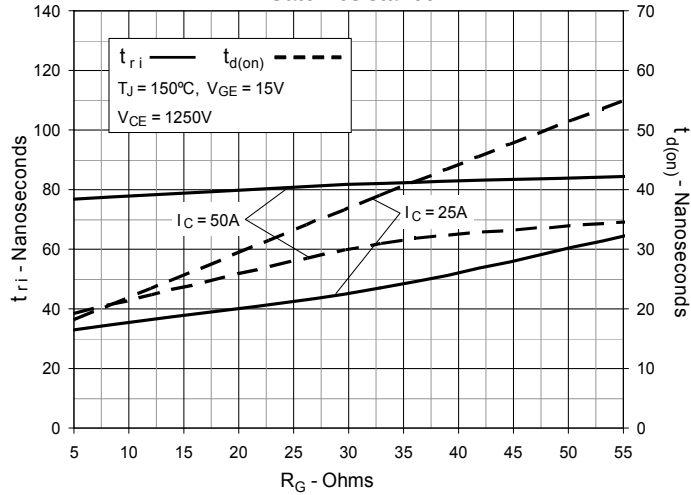


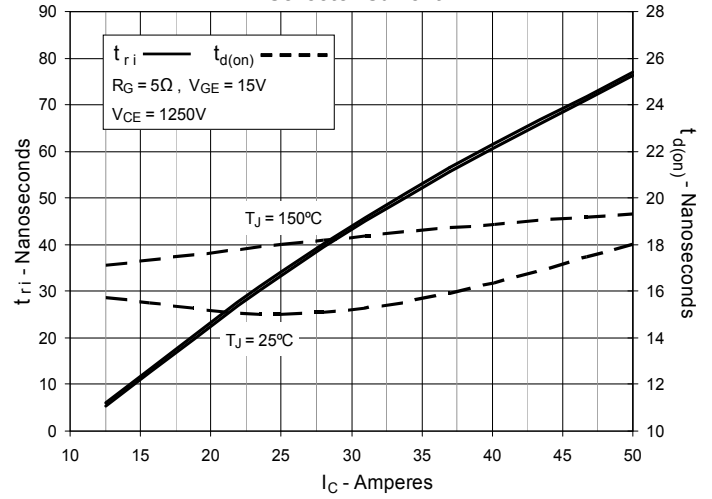
Fig. 18. Inductive Turn-off Switching Times vs. Junction Temperature



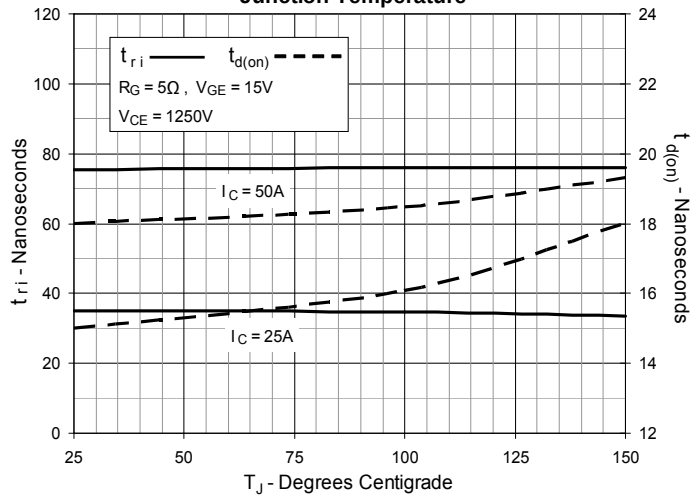
**Fig. 19. Inductive Turn-on Switching Times vs. Gate Resistance**



**Fig. 20. Inductive Turn-on Switching Times vs. Collector Current**



**Fig. 21. Inductive Turn-on Switching Times vs. Junction Temperature**





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